



FMMT458

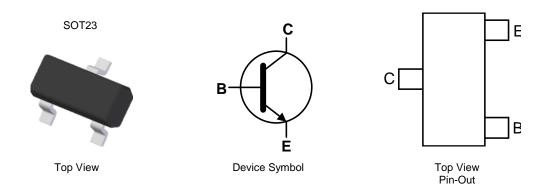
400V NPN HIGH VOLTAGE TRANSISTOR IN SOT23

Features

- BV_{CEO} > 400V
- I_C = 225mA High Continuous Collector Current
- I_{CM} = 1A Peak Pulse Current
- 500mW Power Dissipation
- Excellent h_{FE} Characteristics Up To 100mA
- Complementary PNP Type: FMMT558
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 3
- Weight: 0.008 grams (Approximate)



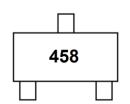
Ordering Information (Notes 4 & 5)

| Part Number | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity Per Reel |
|-------------|------------|---------|--------------------|-----------------|-------------------|
| FMMT458TA | AEC-Q101 | 458 | 7 | 8 | 3,000 |
| FMMT458QTA | Automotive | 458 | 7 | 8 | 3,000 |

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen and Antimony free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Automotive, AEC-Q101 and standard products are electrically and thermally the same, except where specified. For more information, please refer to http://www.diodes.com/product_compliance_definitions.html.
- 5. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



458 = Product Type Marking Code



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 400 | V |
| Collector-Emitter Voltage | V _{CEO} | 400 | V |
| Emitter-Base Voltage | V _{EBO} | 7 | V |
| Continuous Collector Current | Ic | 225 | mA |
| Peak Pulse Current | Ісм | 1 | Α |
| Base Current | I _B | 200 | mA |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|--|-----------------------------------|-------------|------|
| Power Dissipation (Note 6) | P _D | 500 | mW |
| Thermal Resistance, Junction to Ambient (Note 6) | $R_{\theta JA}$ | 250 | °C/W |
| Thermal Resistance, Junction to Lead (Note 7) | $R_{	heta JL}$ | 197 | °C/W |
| Operating and Storage Temperature Range | T _J , T _{STG} | -55 to +150 | °C |

ESD Ratings (Note 8)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge - Human Body Model | ESD HBM | 4,000 | V | 3A |
| Electrostatic Discharge - Machine Model | ESD MM | ≥ 400 | V | С |

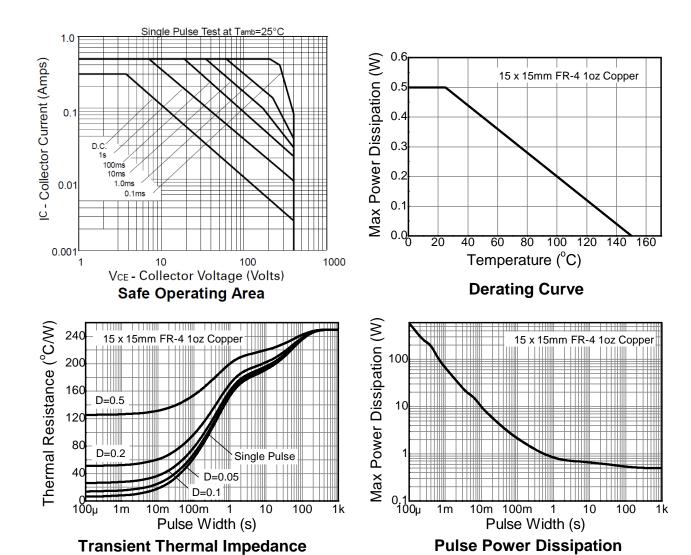
Notes:

- 6. For a device surface mounted on 15mm X 15mm X 1.6mm FR-4 PCB with high coverage of single sided 1oz copper, in still air conditions.
- 7. Thermal resistance from junction to solder-point (at the end of the collector lead).

 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|----------------------|------------------|------|------------|----------|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | 400 | _ | _ | V | $I_C = 100\mu A$ |
| Collector-Emitter Breakdown Voltage (Note 9) | BV _{CEO} | 400 | _ | _ | V | I _C = 10mA |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 7 | _ | _ | V | I _E = 100μA |
| Collector Cutoff Current | I _{CBO} | _ | _ | 100 | nA | V _{CB} = 320V |
| Emitter Cutoff Current | I _{EBO} | _ | _ | 100 | nA | V _{EB} = 5.6V |
| Collector Emitter Cutoff Current | I _{CES} | _ | _ | 100 | nA | V _{CE} = 320V |
| Static Forward Current Transfer Ratio (Note 9) | h _{FE} | 100 100 15 | _ | 300 | _ | $I_{C} = 1$ mA, $V_{CE} = 10$ V $I_{C} = 50$ mA, $V_{CE} = 10$ V $I_{C} = 100$ mA, $V_{CE} = 10$ V |
| Collector-Emitter Saturation Voltage (Note 9) | V _{CE(SAT)} | _ | _ | 200 500 | mV mV | $I_C = 20mA, I_B = 2mA$ $I_C = 50mA, I_B = 6mA$ |
| Base-Emitter Turn-On Voltage (Note 9) | V _{BE(ON)} | _ | _ | 0.9 | V | I _C = 50mA, V _{CE} = 10V |
| Base-Emitter Saturation Voltage (Note 9) | V _{BE(SAT)} | _ | _ | 0.9 | V | $I_C = 50$ mA, $I_B = 5$ mA |
| Output Capacitance | Сово | _ | _ | 5 | pF | V _{CB} = 20V, f = 1MHz |
| Transition Frequency | f⊤ | 50 | _ | _ | MHz | V _{CE} = 20V, I _C = 10mA, f = 20MHz |
| Turn-On Time | t _{ON} | _ | 135 | _ | ns | V _{CE} = 100V, I _C = 50mA |
| Turn-Off Time | t _{OFF} | _ | 2260 | _ | ns | $I_{B1} = 5mA$, $I_{B2} = -10mA$ |

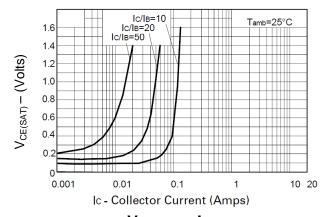
Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.

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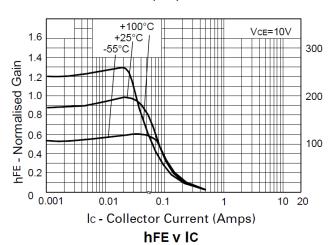
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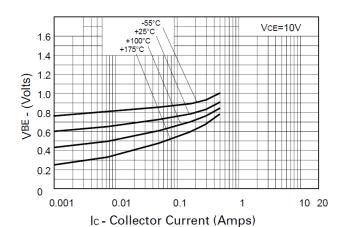


Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

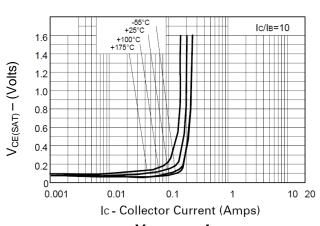




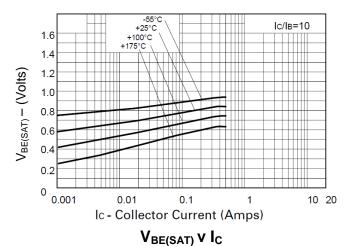




 $V_{BE(ON)} v I_C$



 $V_{CE(SAT)} v I_C$

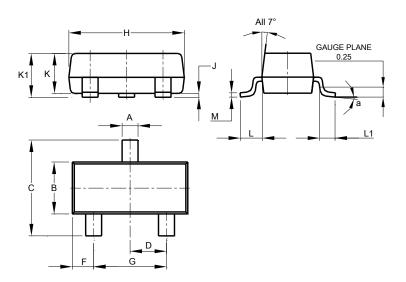




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23

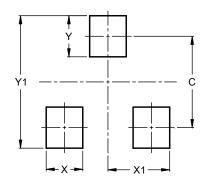


| SOT23 | | | | | |
|----------------------|-------|-------|-------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 0.37 | 0.51 | 0.40 | | |
| В | 1.20 | 1.40 | 1.30 | | |
| C | 2.30 | 2.50 | 2.40 | | |
| D | 0.89 | 1.03 | 0.915 | | |
| F | 0.45 | 0.60 | 0.535 | | |
| G | 1.78 | 2.05 | 1.83 | | |
| Н | 2.80 | 3.00 | 2.90 | | |
| J | 0.013 | 0.10 | 0.05 | | |
| K | 0.890 | 1.00 | 0.975 | | |
| K1 | 0.903 | 1.10 | 1.025 | | |
| L | 0.45 | 0.61 | 0.55 | | |
| L1 | 0.25 | 0.55 | 0.40 | | |
| M | 0.085 | 0.150 | 0.110 | | |
| а | 0° | 8° | | | |
| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



| Dimensions | Value (in mm) | | |
|------------|---------------|--|--|
| С | 2.0 | | |
| Х | 0.8 | | |
| X1 | 1.35 | | |
| Υ | 0.9 | | |
| Y1 | 2.9 | | |



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